Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Glass or plastic

Overall Length:

Between 0.185 inches and 0.260 inches

Terminal Length:

1.000 inches

Overall Diameter:

Between 0.100 inches and 0.120 inches

End Application:

General purpose electronic test equipment gpete, calibration standards equipment, strategic weapon systems (poseidon & trident)

Mounting Method:

Terminal

Criticality Code Justification:

Feat

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

20.0 reverse voltage, instantaneous and 0.55 forward voltage, dc

Current Rating Per Characteristic:

1.00 amperes source cutoff current preset

Maximum Operating Tempurature Per Measurement Point:

125.0 degrees celsius junction

Special Features:

Weapom system essential; junction pattern arrangement: pn

Terminal Type And Quantity:

2 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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